APR 1 0 2002

AMENDMENT TRANSMITTAL LETTER

Docket No. M4065.0319/P319-A

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Application No.	Filing Date	Examiner	Art Unit
09/912,558-Conf. #5990	July 26, 2001	E. Kielin	2813

Applicant(s): Husam N. Al-Shareef, et al.

Invention:

FABRICATION OF DRAM AND OTHER SEMICONDUCTOR DEVICES WITH AN INSULATING FILM USING A WET RAPID THERMAL OXIDATION PROCESS

TO THE COMMISSIONER FOR PATENTS

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

		CLAIM	S AS AMENI	DED	
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
otal Claims	29	- 30 =		×	0.00
ndependent laims	6	- 6 =		х	0.00
lultiple Depen	dent Claims (ch	eck if applicabl	e)		
Other fee (pleas	se specify):				
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Large Entity	/			Small Enti	ty
≓	al fee is require	d for this amer	ndment.		
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A check in t	the amount of \$		to cover	the filing fee is er	nclosed.
The Commi	issioner is herel d below. A dup	by authorized to dicate copy of	o charge and this sheet is e	credit Deposit Adenciosed.	ccount No04-1073
x Credit a	any overpaymer	nt.			
=			on processing t	fees required unde	er 37 CFR 1.16 and 1.17.
<u> </u>	De X			Dated:	April 10, 2002
				Dated:	April 10, 2002
Attorney Reg. DICKSTEIN SI	No.: 28,371 HAPIRO MORII	N & OSHINSK	Y LLP	Dated:	
2101 L Street l Washington, D	No.: 28,371 HAPIRO MORII NW IC 20037-1526		Y LLP	Dated:	
Attorney Reg. DICKSTEIN SI 2101 L Street I	No.: 28,371 HAPIRO MORII NW IC 20037-1526		Y LLP	Dated:	
Attorney Reg. DICKSTEIN SI 2101 L Street I Washington, D	No.: 28,371 HAPIRO MORII NW IC 20037-1526		Y LLP	Dated:	APR 15 20 TECHNOLOGY CENTE